

SANYO

No.429D

2SC1755, 1756, 1757

NPN Triple Diffused Planar Silicon Transistors
 FOR CHROMA OUTPUT & AF OUTPUT OF COLOR TV
 FOR VIDEO OUTPUT & AF OUTPUT OF B/W TV

These 2SC1755, 1756, 1757 are different only from their packages.

Absolute Maximum Ratings at Ta=25°C

Collector to Base Voltage	V _{CB0}	300	V	
Collector to Emitter Voltage	V _{CE0}	300	V	
Emitter to Base Voltage	V _{EB0}	7	V	
Collector Current	I _C	200	mA	
Peak Collector Current	i _{cp}	700	mA	
Collector Dissipation	P _C	1.2	W	
	P _C	T _C =25°C	15	W
Junction Temperature	T _j	150	°C	
Storage Temperature	T _{stg}	-40 to +150	°C	

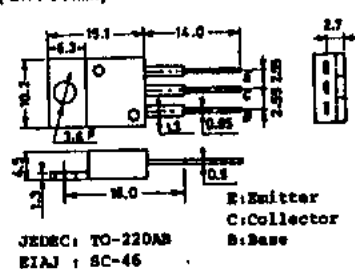
Electrical Characteristics at Ta=25°C

			min	typ	max	unit
Collector Cutoff Current	I _{CB0}	V _{CB} =200V, I _E =0			0.1	uA
Emitter Cutoff Current	I _{EB0}	V _{EB} =5V, I _C =0			0.1	uA
DC Current Gain	h _{FE}	V _{CE} =10V, I _C =10mA	40*		200*	
Gain Bandwidth Product	f _T	V _{CE} =30V, I _C =10mA	50			MHz
Output Capacitance	C _{ob}	V _{CB} =50V, f=1MHz			5.3	pF
C-E Saturation Voltage	V _{CE(sat)}	I _C =50mA, I _B =5mA			2.0	V

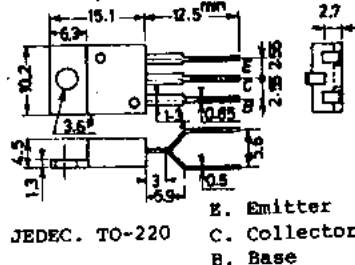
* The 2SC1755, 1756, 1757 are classified as follows.

40	C	80	60	D	120	100	E	200
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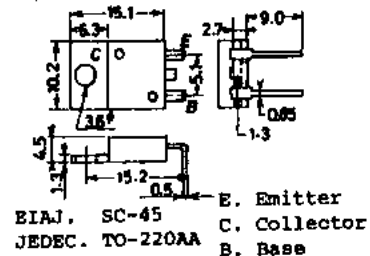
Case Outline 2010A
(unit:mm)



Case Outline 2013
(unit:mm)

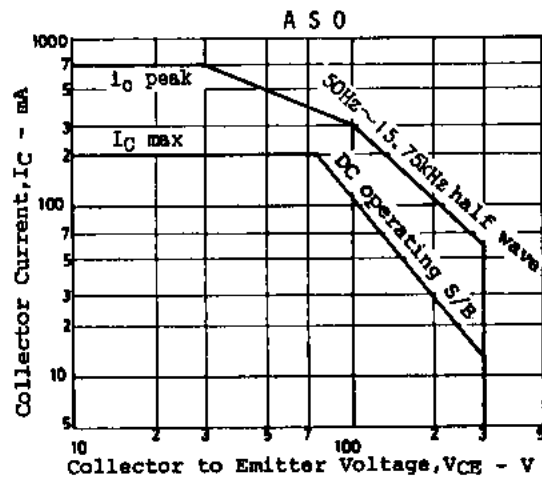
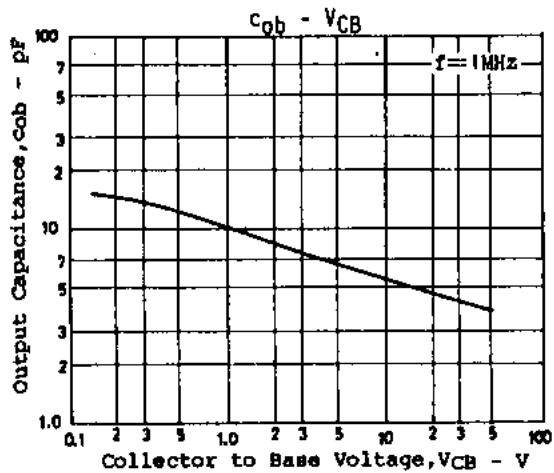
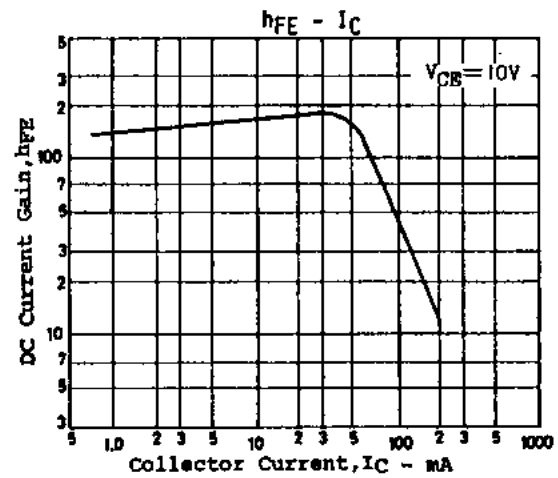
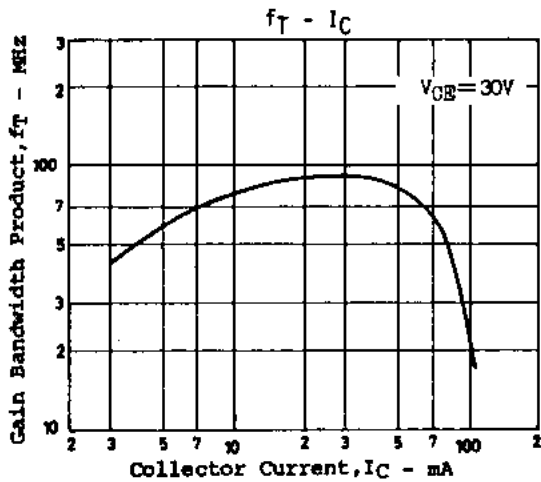
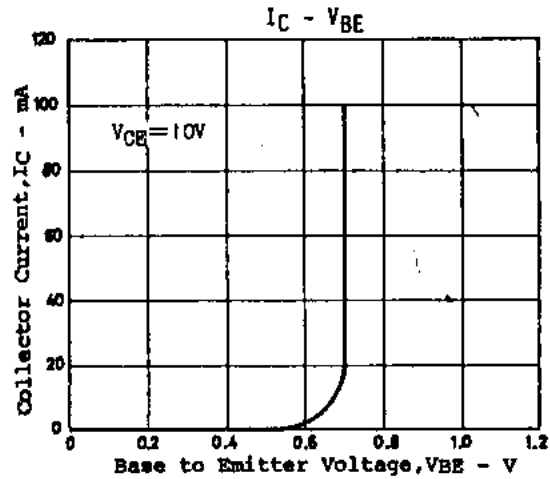
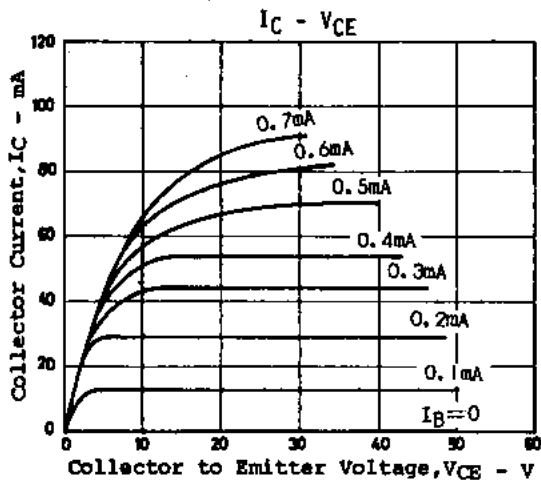


Case Outline 2012
(unit:mm)



These specifications are subject to change without notice.

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